

**TO - 92 BIPOLAR TRANSISTORS
TRANSISTOR(NPN)**

FEATURES

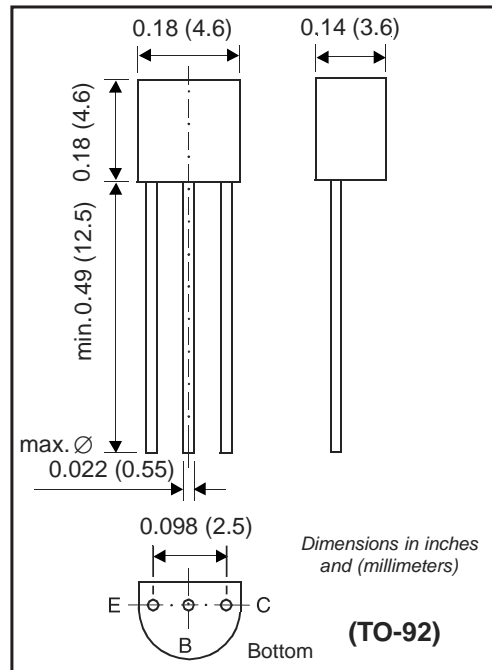
- * Power dissipation
P_{CM}: 625mW(T_{amb}=25°C)
- * Collector current
I_{CM}: 0.6 A
- * Collector-base voltage
V_{(BR)CBO}: 75 V
- * Operating and storage junction temperature range
T_J, T_{stg}: -55°C to +150°C

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-O rate flame retardant
- * Lead: MIL-STD-202E method 208C guaranteed
- * Mounting position: Any
- * Weight: 0.008 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.



MAXIMUM RATINGS (@ T_A = 25°C unless otherwise noted)

RATINGS	SYMBOL	VALUE	UNITS
Max. Steady State Power Dissipation ⁽¹⁾ @T _A =25°C Derate above 25°C	P _D	625	mW
Max. Operating Temperature Range	T _J	150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (@ T_A = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS
Thermal Resistance Junction to Ambient	R _{θJA}	-	-	200	°C/W

Notes : 1. Alumina=0.4*0.3*0.024in.99.5% alumina
2. "Fully ROHS Compliant", "100% Sn plating (Pb-free)".

ELECTRICAL CHARACTERISTICS (@TA=25°C unless otherwise noted)

Chatacteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ($I_C = 10\text{mA}$, $I_B = 0$)	$V_{(BR)CEO}$	40	-	Vdc
Collector-Base Breakdown Voltage ($I_C = 10\text{uA}$, $I_E = 0$)	$V_{(BR)CBO}$	75	-	Vdc
Emitter-Base Breakdown Voltage ($I_E = 10\text{uA}$, $I_C = 0$)	$V_{(BR)EBO}$	6.0	-	Vdc
Collector Cutoff Current ($V_{CE} = 60\text{Vdc}$, $V_{EB(off)} = 3.0\text{Vdc}$)	I_{CEX}	-	0.01	uAdc
Collector Cutoff Current ($V_{CB} = 60\text{Vdc}$, $I_E = 0$) ($V_{CB} = 60\text{Vdc}$, $I_E = 0$, $T_A = 150^\circ\text{C}$)	I_{CBO}	-	0.01 10	uAdc
Emitter Cutoff Current ($V_{EB} = 3.0\text{Vdc}$, $I_C = 0$)	I_{EBO}	-	0.01	uAdc
Base Cutoff Current ($V_{CE} = 60\text{Vdc}$, $V_{EB(off)} = 3.0\text{Vdc}$)	I_{BL}	-	20	nAdc

ON CHARACTERISTICS

DC Current Gain ($I_C = 10\text{mA}$, $V_{CE} = 10\text{Vdc}$, $T_A = -55^\circ\text{C}$) ($I_C = 500\text{mA}$, $V_{CE} = 10\text{Vdc}$) (1)	hFE	35 40	- -	-
Collector-Emitter Saturation Voltage (1) ($I_C = 150\text{mA}$, $I_B = 15\text{mA}$) ($I_C = 500\text{mA}$, $I_B = 50\text{mA}$)	$V_{CE(sat)}$	- -	0.3 1.0	Vdc
Base-Emitter Saturation Voltage (1) ($I_C = 150\text{mA}$, $I_B = 15\text{mA}$) ($I_C = 500\text{mA}$, $I_B = 50\text{mA}$)	$V_{BE(sat)}$	0.6 -	1.2 2.0	Vdc

SMALL-SIGNAL CHARACTERISTICS

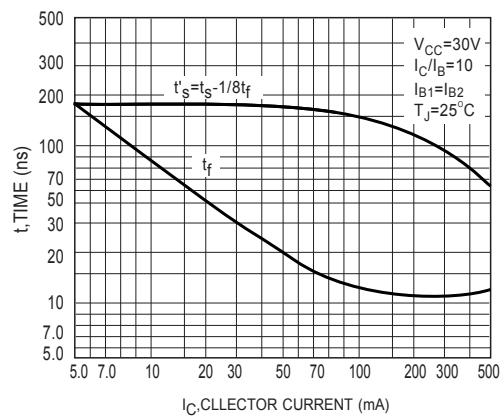
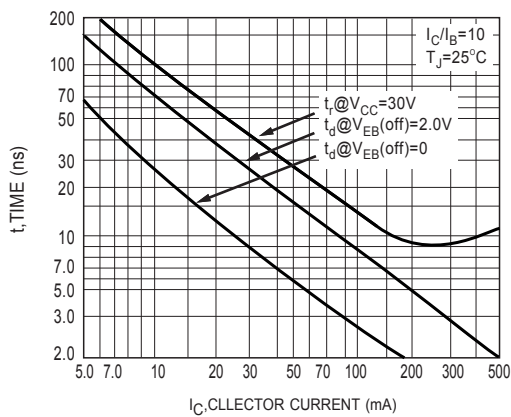
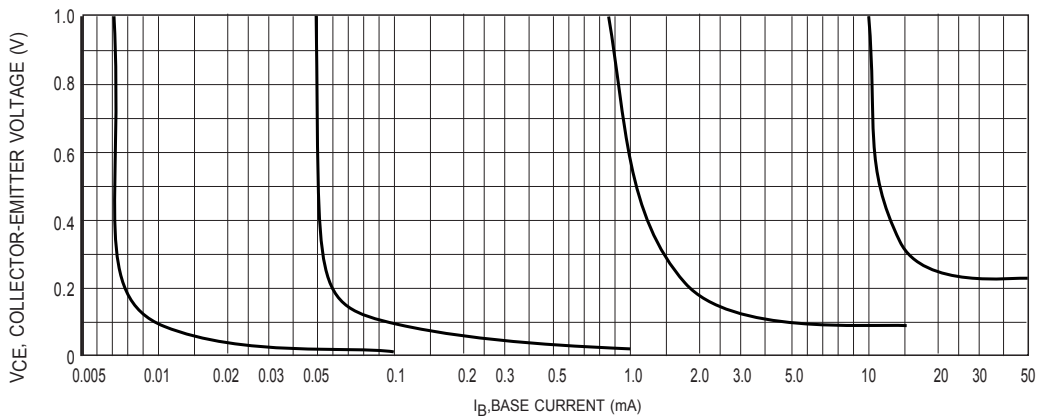
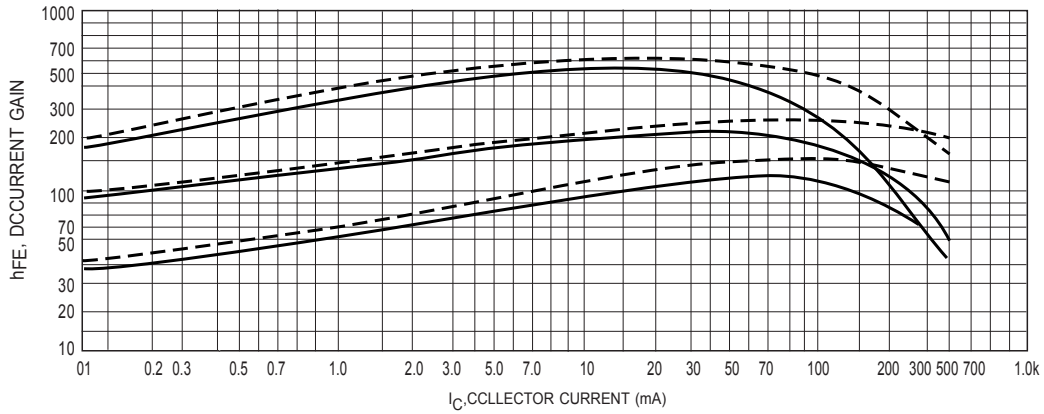
Current-Gain-Bandwidth Product (2) ($I_C = 20\text{mA}$, $V_{CE} = 20\text{Vdc}$, $f = 100\text{MHz}$)	f_T	300	-	MHz
Input Capacitance ($V_{EB} = 0.5\text{Vdc}$, $I_C = 0$, $f = 1.0\text{MHz}$)	C_{ibo}	-	25	pF
Input Impedance ($I_C = 1.0\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$) ($I_C = 10\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$)	h_{ie}	2.0 0.25	8.0 1.25	kohms
Voltage Feedback Ratio ($I_C = 1.0\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$) ($I_C = 10\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$)	h_{re}	- -	8.0 4.0	$\times 10^{-4}$
Small-Signal Current Gain ($I_C = 1.0\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$) ($I_C = 10\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$)	h_{fe}	50 75	300 375	-
Output Admittance ($I_C = 1.0\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$) ($I_C = 10\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$)	h_{oe}	5.0 25	35 200	umhos
Collector Base Time Constant ($I_E = 20\text{mA}$, $V_{CB} = 20\text{Vdc}$, $f = 31.8\text{MHz}$)	$\tau_{b,Cc}$	-	150	ps
Noise Figure ($I_C = 100\text{uA}$, $V_{CE} = 10\text{Vdc}$, $R_S = 1.0\text{kohms}$, $f = 1.0\text{kHz}$)	NF	-	4.0	dB

SWITCHING CHARACTERISTICS

Delay Time Rise Time	($V_{CC} = 30\text{Vdc}$, $V_{BE(off)} = -0.5\text{Vdc}$, $I_C = 150\text{mA}$, $I_{B1} = 15\text{mA}$)	t_d t_r	- -	10 25	ns
Storage Time Fall Time	($V_{CC} = 30\text{Vdc}$, $I_C = 150\text{mA}$, $I_{B1} = I_{B2} = 15\text{mA}$)	t_s t_f	- -	225 60	ns

NOTES : 1. Pulse Test: Pulse Width ≤ 300ms, Duty Cycle ≤ 2.0%
2. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity

RATING AND CHARACTERISTICS CURVES (PN2222A)



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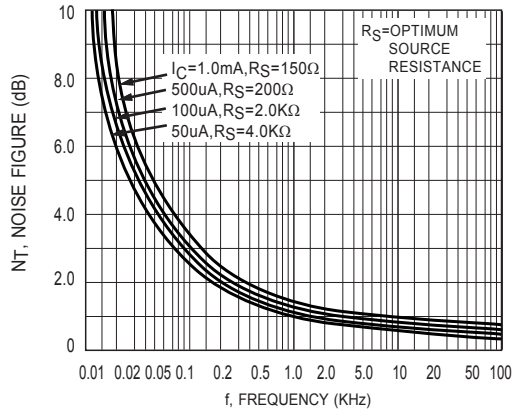


Figure 5. Frequency Effects

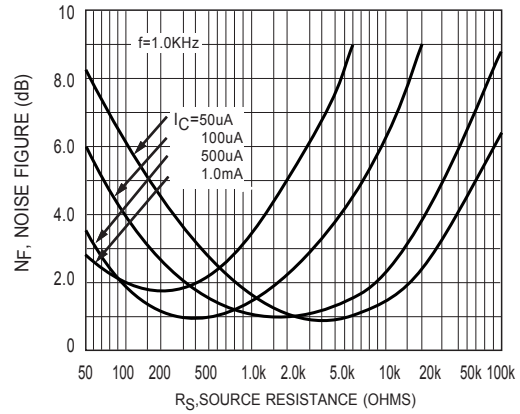


Figure 6. Source Resistance Effects

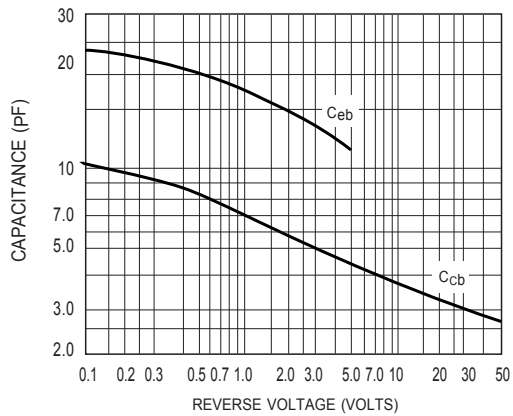


Figure 7. Capacitances

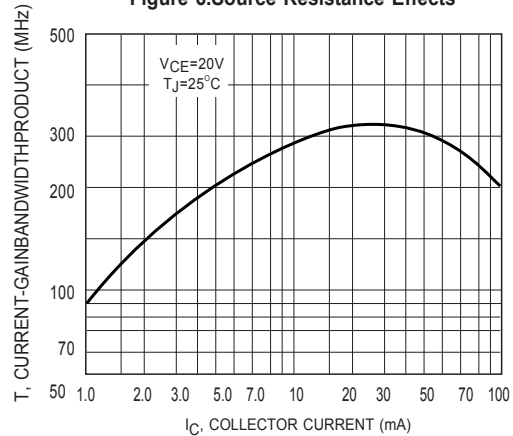


Figure 8. Current-Gain Bandwidth Product

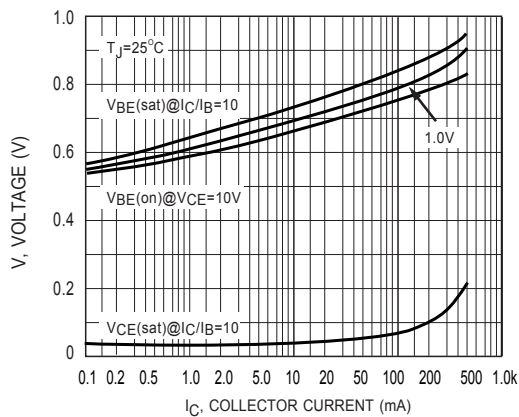


Figure 9. "On" Voltages

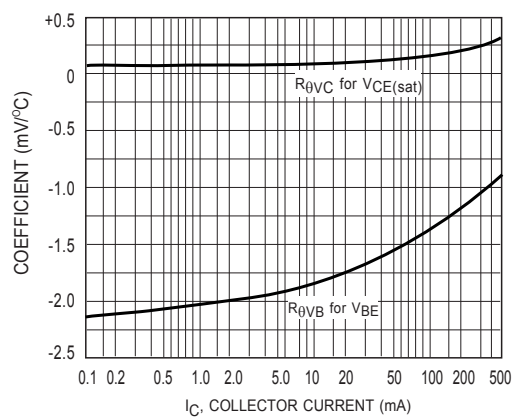


Figure 10. Temperature Coefficients

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- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
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